EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	10/540410	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/27 15:37
L2	8	("20020153527"|"5576556"|"5786241"|"6410373").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/27 15:38
L3	86	("20020153527"|"5576556"|"5786241"|"6410373")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/27 15:56
L4	9	("20010015441" | "20010025992" | "20010048107" | "20020001886" | "5403761" | "6228692" | "6259138" | "6303963" | "6331723").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 15:49
L5	9	("20010015441" | "20010025992" | "20010048107" | "20020001886" | "5403761" | "6228692" | "6259138" | "6303963" | "6331723").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 17:01
L6	173193	transistor with gate	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 17:01
L7	116939	transistor with gate same (source drain)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 17:01

L8	356	transistor with gate same (source drain) with (sidewall side adj wall wall near3 spacer) near5 (metal metallic conductive)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:19
L9	58	S8 and "LDD" same (source drain) with (sidewall side adj wall wall near3 spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:19
L10	18	S9 and (source drain) with (silicide)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:14
L12	8028	gate same (metal metallic conductive polysilicon) near3 (sidewall side near3 wall wall near3 spacer spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:22
L13	289	S12 and transistor with gate same (source drain) with (sidewall side adj wall wall near3 spacer) near5 (metal metallic conductive)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:23
L14	50	S13 and "LDD" same (source drain) with (sidewall side adj wall wall near3 spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:23
L15	8028	gate same (metal metallic conductive polysilicon) near3 (sidewall side near3 wall wall near3 spacer spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:21
L16	5995	gate same (metal metallic conductive polysilicon) near2 (sidewall side near3 wall wall near3 spacer spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:22
L17	3619	gate same (metal metallic conductive polysilicon) near (sidewall side near3 wall wall near3 spacer spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:22
L18	119	S17 and transistor with gate same (source drain) with (sidewall side adj wall wall near3 spacer) near5 (metal metallic conductive)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:23
L19	30	S18 and "LDD" same (source drain) with (sidewall side adj wall wall near3 spacer)	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/27 17:23

L20	5	("5039621" | "5254490" | "5439846" | "5739066" | "6103590").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 17:39
L21	6	("4521448" | "4727038" | "4804636" | "4868617" | "4925807" | "4971922").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 17:46
L22	13	("4488351" | "4587718" | "4613882" | "4616401" | "4658496" | "4680603" | "4703551" | "4727038" | "4735680" | "4753898" | "4788160" | "4824796" | "4835112").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 17:50
L23	4	("4363696" | "4597824" | "4654680" | "4746219").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 18:03
L24	12	("4510670" | "4526665" | "4528744" | "4541166" | "4558507" | "4563805" | "4575920" | "4585517" | "4587710" | "4593454" | "4613882" | "4622735").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 18:15
L25	35	"4925807"	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/27 18:15